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# A Novel DC-DC Boost Converter Design for Higher Conversion Efficiency

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## Introduction

A boost converter (step-up converter) is a power converter with an output DC voltage greater than its input DC voltage. It is a class of switching-mode power supply (SMPS) containing at least two semiconductor switches (a diode and a transistor) and at least one energy storage element. Filters made of capacitors (sometimes in combination with inductors) are normally added to the output of the converter to reduce output voltage ripple (Rashid, 2001).

Boost converter operation may cause serious reverse-recovery problems and increase the rating of all devices. As a result, the conversion efficiency is degraded and may result in severe electromagnetic interference problem under this situation (Khatib, 2010, Khatib, 2010(1), AlSadi, 2012, Mohan, 1995, Jovanovic, 1999, Duarte, 2002).. To overcome the severe reverse-recovery problem of high voltage diodes, voltage-clamped technique is manipulated in the converter design. However,

this technique causes voltage stress on the switches and voltage gain is limited by the turnon time of the auxiliary switch (Khatib, 2010, Khatib, 2010(1), Mohan, 1995, Jovanovic, 1999, Duarte, 2002, Roh, 2003). Another problem in boost converter operation is the leakage energy of the storage inductor which is generated by the turning off action of the converter switches. It will result in a highvoltage ripple across the switch due to the resonant phenomenon induced by the leakage current. Therefore, to protect the converter switching devices, two mitigating actions can be taken, that is, by using a high voltage rating device with a snubber circuit and by depleting the inductor leakage energy. In order to increase the conversion efficiency, many modified boost converter topologies have been investigated (Roh, 2003, Zhao, 2003, Tseng, 2004).

In this paper, a new boost converter circuit has been developed by adding diodes and capacitors to the conventional converter circuit to transmit

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## Abstract

This paper presents the development of a DC-DC boost converter. In the proposed boost converter design, a passive regenerative snubber circuit is included to absorb the energy of stray inductance so as to reduce the IGBT switching losses. MATLAB simulation as well as an experiment results are conducted to validate the proposed device. The results show that the proposed boost converter design gives an efficiency of 93% which is better than the conventional converter (88%). and sink the leakage energy of the inductor during transient switching.

## **Proposed Boost Converter**

A boost converter is the front-end component of a PV system connected between a PV array and a load. It is basically a power converter with DC output voltage greater than its input voltage. It is a class of switching-mode power supply containing at least two semiconductor switches, a diode and a transistor and at least one energy storage element. Filters made of capacitors in combination with inductors are normally added to the output of the converter to reduce the output voltage ripple (Rashid, 2001). An inherent problem in boost converters is that it may cause serious reverse recovery problem which may increase the rating of devices and degrade the conversion. To increase the conversion efficiency, an improvement is made in the boost converter design. Figure 1 shows the MPPT controller with the proposed boost converter design. The converter consists of an inductor in the primary side (L), clamping diodes, D1,D2, capacitor C2 used to form a regenerative circuit to sink the reverse recovery current and an output filter circuit using diode, Do and capacitor, Co.

To describe the operation of the boost converter, four modes of operation are considered. Figure 2 shows the triggering signal of the converter's switch operating at the four modes of operation.

1. Mode 2 operation - In this mode, the switch Q is turned off and the current, IL will start to charge the parasitic capacitor of the switch Q as shown in Fig. 3b. When the switch voltage is greater than the clamped capacitor voltage, VC1, the clamping diode, D1 will conduct and transmit the energy of the leakage inductor LK into the clamped capacitor, C1. C1 is assumed to be large enough with favorable high frequency response so that its voltage, VC1 can be viewed as a stable DC output with low ripple for clamping the maximum value of the switch voltage. In addition, D1 should be a fast conductive device with voltage rating similar to the Switch Q.

- Mode 3 operation this mode of operation is illustrated as in Fig. 3c in which the switch is turned off and the reverse parasitic voltage of the output diode, Do decays to zero. At this time, Do starts to conduct and the rectifier diode, D2 is cut off. The series voltages, VLK and VLm will charge the output capacitor, Co and supply current to the load.
- 3. Mode 4 operation At this time, the switch Q is turned on (Figure 3d) and the clamping diode, D1 is cut off promptly without reverse recovery current because it has a low voltage. The switch Q is turned on under zero current switching because the current, 11 is limited by the leakage inductor, Lk and it cannot derive any current from the inductor side or the passive regenerative snubber circuit side. This soft switching is helpful for reducing the switching losses.

#### **Boost Converter Analysis**

For boost converter analysis, the Mode 1 and Mode 3 operations for the ON and OFF switching states respectively are taken into consideration. As the switching boost converter is time variant and topology variant, the defining equations of the circuit are put in the following forms (Xu, 1991).

At Mode 1, during the time interval of 0 < t < T, it can be observed that,

$$L\frac{dI_{L}(t)}{dt} = V_{in}(t) \quad (5)$$
$$C_{o} \frac{dV_{C_{o}}(t)}{dt} = -\frac{V_{C_{o}}(t)}{R} (6)$$

At Mode 3, during the time interval of T < t < T+n, the equations for the circuit are defined as, I  $\frac{dI_L(t)}{dI_L(t)} = V_{c1}(t) - V_{c2}(t)$  (7)

$$C_{o} \frac{dv_{C}(t)}{dt} = I_{L}(t) - \frac{v_{C_{o}}(t)}{R}$$
(8)

Define a time variant control input variable,  $\delta$  (t) which is given by,

$$\delta(t) = \begin{cases} 1, & \xrightarrow{if} 0 < t < T \\ -, & \xrightarrow{if} T < t < T + n \end{cases}$$
(9)

By considering  $\delta(t)$  and substituting it into equations (7) and (8), the defining equations of

the time variant and topology variant circuit becomes,

$$L\frac{dI_{L}(t)}{dt} = V_{in}(t) - [V_{C}(t)x(1 - \delta(t))] \quad (10)$$

$$C_{o} \frac{dV_{C_{0}}(t)}{dt} = [I_{L}(t)x(1 - \delta(t))] - \frac{V_{C_{0}}(t)}{R} \quad (11)$$
To perform DC steady state and AC small signal analysis, the variables  $V_{c}$ ,  $I_{L}$ ,  $V_{in}$  and  $\delta$  are defined as having two components which are the DC component and the corresponding perturbation component (Rashid, 2001). If the DC components are represented by the letters with non hat symbol and the perturbation components are represented by the letters with hat symbol, equations (10) and (11) become,  $dt_{0}^{(t)}$ 

$$L\frac{dt_{1}(t)}{dt} = V_{in} + \bar{V}_{in}(t) - (V_{C_0} + \bar{V}_{C_0}(t)) ((1-D) - (1-\hat{d}(t))) (12)$$

$$C\frac{d\bar{V}_0(t)}{dt} = I_L + \bar{I}_{1L}(t) \left( (1-D) - (1-\hat{d}(t)) \right) - \frac{V_c + \bar{V}_c(t)}{R} (13)$$

where, D is the duty cycle. To perform DC steady state analysis, let

$$\overline{V_{c_{0'}}} \widehat{I_{L'}} \overline{V_{in}}$$
 and  $\widehat{d} = 0$  and  $V_{c_{0}} = V_{o}$ .

Then equations (12) and (13) become,

$$V_{in} - Vo(1 - D) = 0 (14)$$
  
$$I_L(1 - D) - \frac{V_0}{R} = 0 (15)$$

From equations (14) and (15), the relation between the input and the output voltages of the boost converter will be:

$$\frac{\mathbf{v}_0}{\mathbf{v}_{\text{in}}} = \frac{\mathbf{1}}{\mathbf{1} - \mathbf{D}} \quad (16)$$

And

$$I_{L} = \frac{V_{in}}{R_{load} \left[1-D\right]^{2}} \qquad (17)$$

Assuming that the converter is ideal in which output power is equal to the input power,

$$P_{out} = P_{in}, \text{ we get,} V_{in} X I_{in} = V_o X I_o \quad (18)$$

Substituting equation (15) into (17), we get the current gain equation of the boost converter which is given by,

$$\frac{\mathbf{v}_{\text{in}}}{\mathbf{v}_{\text{o}}} = \frac{\mathbf{I}_{\text{o}}}{\mathbf{I}_{\text{in}}} = \begin{bmatrix} \mathbf{1} - \mathbf{D} \end{bmatrix} \quad (19)$$

# **Results and discussion**

A MATLAB simulink of the boost converter was done by considering the converter component values of C1 = 6.8  $\mu$ F, Co = 680  $\mu$ F and L=9  $\mu$ H based on the equations (12) and (13), D1, D2 and Do are the Schottky diodes and Q is a MOSFET IRFP2907, with frequency f = 20 kHz. The performance of the proposed converter is tested using a 25V/300 Watt load. Figure 5.3a shows the output current and voltage of the boost converter. It is noticed that both, the voltage and the current reached their steady state values in .2 seconds. Figure 4 shows the duty cycle of the triggering signal, the duty the duty cycle is 20%.

Figures 6 and 7 show the converter simulation results in terms of its voltage gain  $(V_{out}/V_{in})$ and efficiency  $(P_{out}/P_{in})$ , respectively. As for the voltage gain of the proposed boost converter, the added capacitor, C1 does not seem to affect the voltage gain because it is in parallel with the output capacitor at the reverse mode of operation. The maximum efficiency of the converter is approximately 93%, for the converter to drive a 100 - 800 W load and thus the converter is considered to be efficient compared with the conventional boost converter with an efficiency of 88% (Mohan, 1995). The performance of the boost converter is first tested by using the oscilloscope to measure the output voltage and the duty cycle of the converter. A 20 A current probe is also used to measure the output current. Figure 8 shows the boost converter output voltage at the solar noon in which the output voltage is 25 V for an input voltage of 21.2 volt. The output current is 10.2 A and the calculated conversion efficiency is 90.9 %. Figure 9 shows the duty cycle of the triggering signal which is found to be 28 %  $(14\mu s/50\mu s).$ 

Table 1 shows a comparison between the performances of the boost converter using the MATLAB simulink and the real circuit testing. From the table, it is noted that conversion efficiency of the boost converter in the real test is slightly less than the conversion efficiency in the simulation. Moreover, the duty cycle in the real test is higher than the one obtained from the simulation. The differences in the results are due to the assumption made in simulation which considers ideal circuit elements and no losses. The input and the output voltages are almost same where the output power is slightly different. The difference in the output power is due to the variation in the load. The load in the simulation is exactly 300 Watt where in real test the load varies. the energy of stray inductance. The sunnber circuit is consisted of two diodes and two capacitors. However, MATLAB simulation as well as an experiment results have been performed in order to test the proposed boost converter. The results showed that the proposed boost converter design has a better efficiency of about 93% compared to the conventional converter with efficiency of 88%.

## Conclusion

In this paper, a novel boost converter was presented. A snubber circuit has been added to reduce the IGBT switching losses by absorbing



Figure-1 Proposed boost converter





Figure-3a Mode 1 operation of boost converter



Figure-3 b Mode 2 operation of boost converter



Figure-3 c Mode 3 operation of boost converter



Figure-3 d Mode 4 operation of boost converter







Figure-5 Triggering duty cycle



Figure-8 Output voltage of the boost converter during testing (reading\*10)



Table-1 Comparing the simulation and experimental results of the boost converter

	Simulation	Experimental
Output voltage	25 V	24.9V
Input voltage	21 V	21.2 V
Output power	300 Watt	249 Watt
Conversion efficiency	92.6 %	90.9 %
Duty cycle	20%	28%

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